

SPECIFICATION

Device Name : Power Integrated Module

Type Name : 7MBR15SA140

Spec. No. : MS6M0472

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Fuji Electric Co., Ltd.
Matsumoto Factory

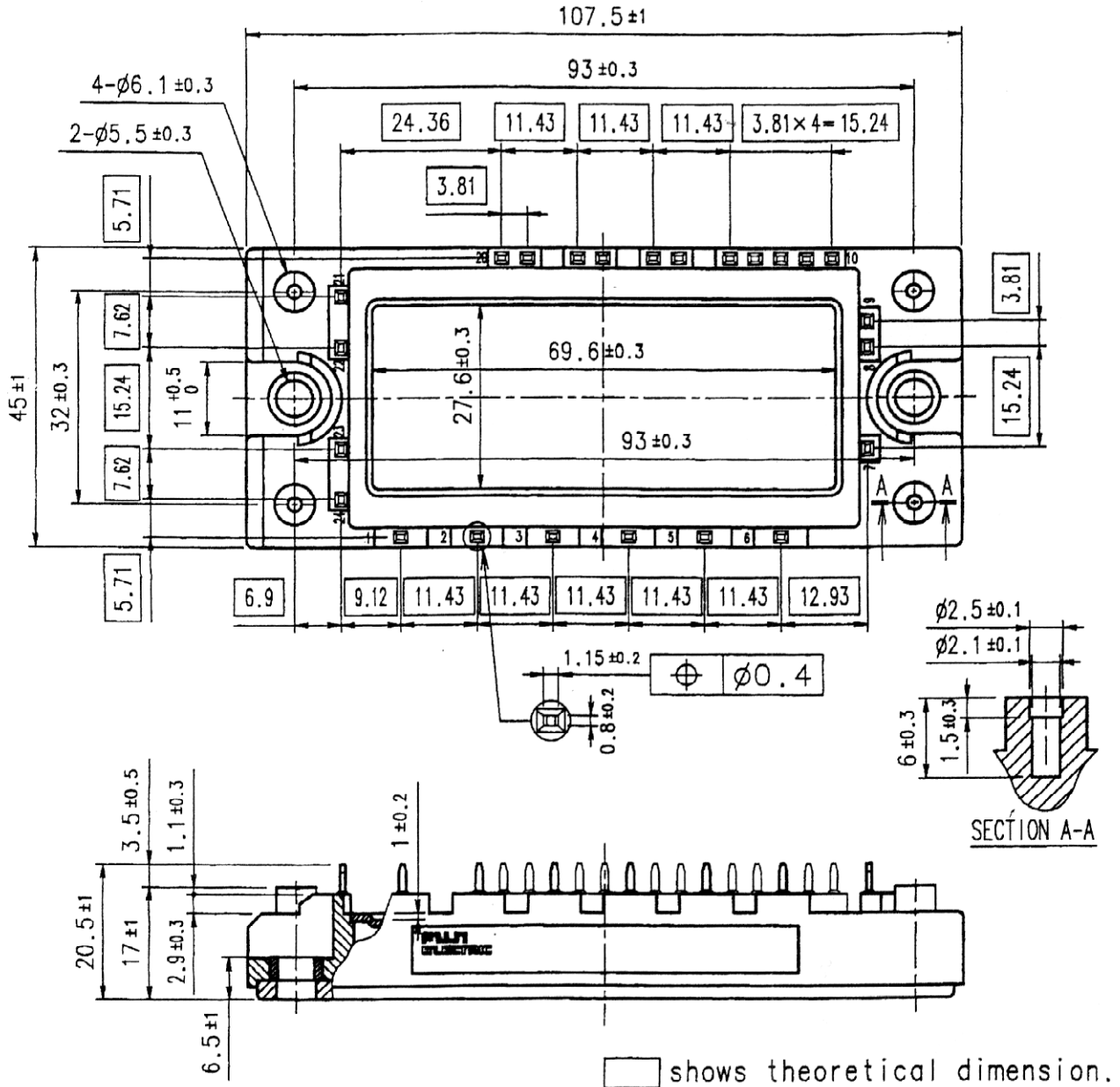


DATE	NAME	APPROVED
DRAWN Nov.-10-'99	T. Kobayashi	
CHECKED Nov.-10-'99	S. Mita	

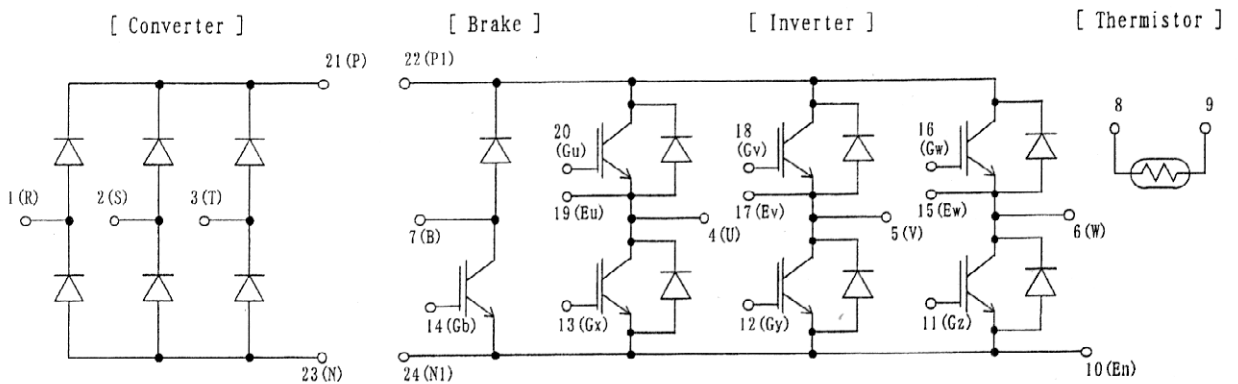
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G.M.O.	MS6M0472	1/1

7MBR15SA140

1. Outline Drawing (Unit : mm)



2. Equivalent circuit



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3. Absolute Maximum Ratings (at Tc= 25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Inverter	Collector-Emitter voltage	V _{CE} S			1400	V
	Gate-Emitter voltage	V _{GE} S			±20	V
	Collector current	I _c	Continuous	T _c =25°C	25	A
				T _c =75°C	15	
		I _{cp}	1ms	T _c =25°C	50	A
				T _c =75°C	30	
-I _c			15	A		
Collector Power Dissipation	P _c	1 device		110	W	
Brake	Collector-Emitter voltage	V _{CE} S			1400	V
	Gate-Emitter voltage	V _{GE} S			±20	V
	Collector current	I _c	Continuous	T _c =25°C	25	A
				T _c =75°C	15	
		I _{cp}	1ms	T _c =25°C	50	A
				T _c =75°C	30	
Collector Power Dissipation	P _c	1 device		110	W	
Repetitive peak reverse Voltage (Diode)	V _{RRM}			1400	V	
Converter	Repetitive peak reverse Voltage	V _{RRM}			1600	V
	Average Output Current	I _o	50Hz/60Hz sine wave		15	A
	Surge Current (Non-Repetitive)	I _{FSM}	T _j =150°C, 10ms		155	A
	I ² t (Non-Repetitive)	I ² t	half sine wave		120	A ² s
Junction temperature	T _j			150	°C	
Storage temperature	T _{stg}			-40~ +125	°C	
Isolation voltage	between terminal and copper base ^(*1)	Viso	AC : 1min.		2500	V
	between thermistor and others ^(*2)				2500	V
Mounting Screw Torque ^(*3)					3.5	N·m

(*1) All terminals should be connected together when isolation test will be done.

(*2) Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(*3) Recommendable Value : 2.5~3.5 N·m (M5)

4. Electrical characteristics (at Tj= 25°C unless otherwise specified)

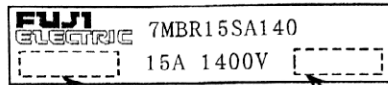
Items	Symbols	Conditions	Characteristics			Units		
			min.	typ.	Max.			
Inverter	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE = 1400 V		1.0	mA		
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE = ±20 V		200	nA		
	Gate-Emitter threshold voltage	VGE(th)	VCE = 20 V, Ic = 15 mA		5.5	7.2	8.5	V
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V,	chip	2.2		V	
			Ic = 15 A	terminal	2.25	2.7		
	Input capacitance	Cies	VGE = 0 V, VCE = 10 V f = 1 MHz		1800		pF	
	Turn-on time	ton	Vcc = 800 V		0.35	1.2	μs	
		tr	Ic = 15 A		0.25	0.6		
		tr(i)	VGE = ±15 V		0.1			
	Turn-off time	toff	RG = 82 Ω		0.45	1.0	μs	
tf				0.08	0.3			
Forward on voltage	VF	IF = 15 A	chip	2.4		V		
			terminal	2.45	3.3			
Reverse recovery time	trr	IF = 15 A			350	ns		
Brake	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE = 1400 V		1.0	mA		
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE = ±20 V		200	nA		
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V,	chip	2.2		V	
			Ic = 15 A	terminal	2.3	2.7		
	Turn-on time	ton	Vcc = 800 V		0.35	1.2	μs	
		tr	Ic = 15 A		0.25	0.6		
Turn-off time	toff	VGE = ±15 V		0.45	1.0	μs		
	tf	RG = 82 Ω		0.08	0.3			
Reverse current	IRRM	VR = 1400 V			1.0	mA		
Converter	Forward on voltage	VFM	IF = 15 A	chip	1.1		V	
				terminal	1.2	1.5		
Reverse current	IRRM	VR = 1600 V			1.0	mA		
Thermistor	Resistance	R	T = 25°C		5000		Ω	
			T = 100°C		465	495		520
B value	B	T = 25/50°C		3305	3375	3450	K	

5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			1.14	°C/W
		Inverter FWD			1.85	
		Brake IGBT			1.14	
		Converter Diode			1.30	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound (※)		0.05		°C/W

※ This is the value which is defined mounting on the additional cooling fin with thermal compound.

6. Indication on module (モジュール表示)



Lot No.

Place of manufacturing (code)

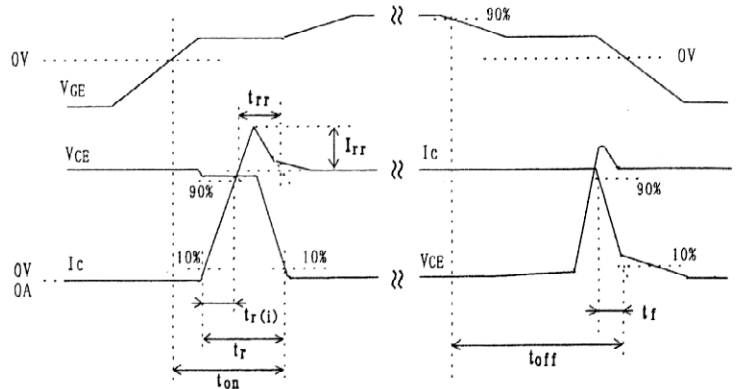
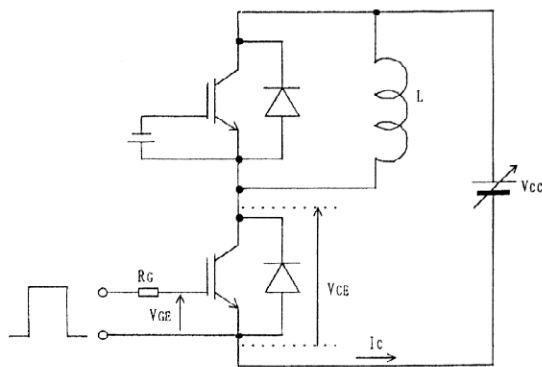
7. Applicable category (適用範囲)

This specification is applied to Power Integrated Module named 7MBR15SA140 .
 本納入仕様書は パワー集積モジュール 7MBR15SA140 に適用する。

8. Storage and transportation notes (保管・運搬上の注意事項)

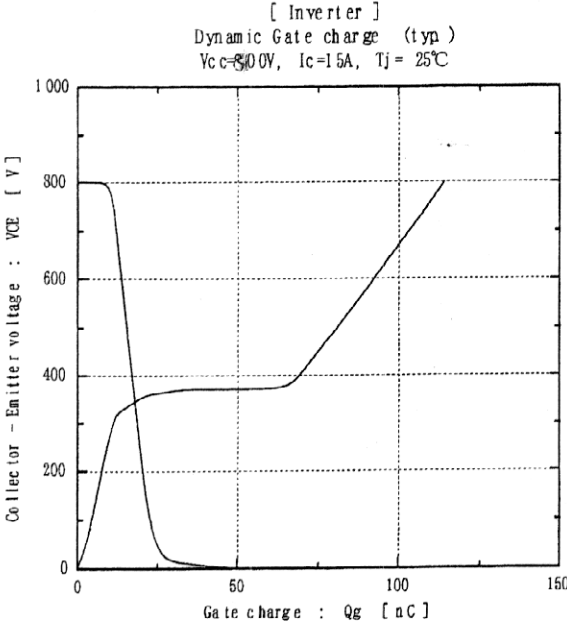
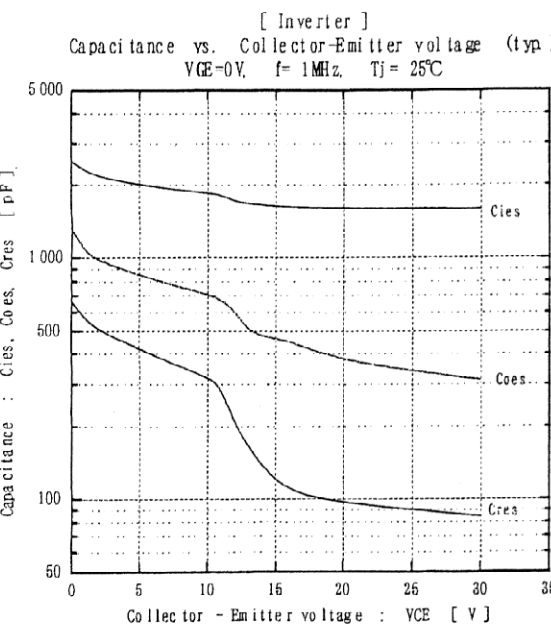
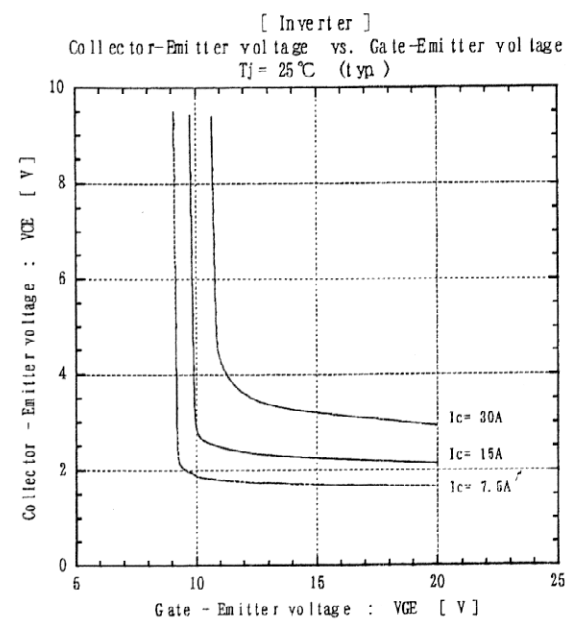
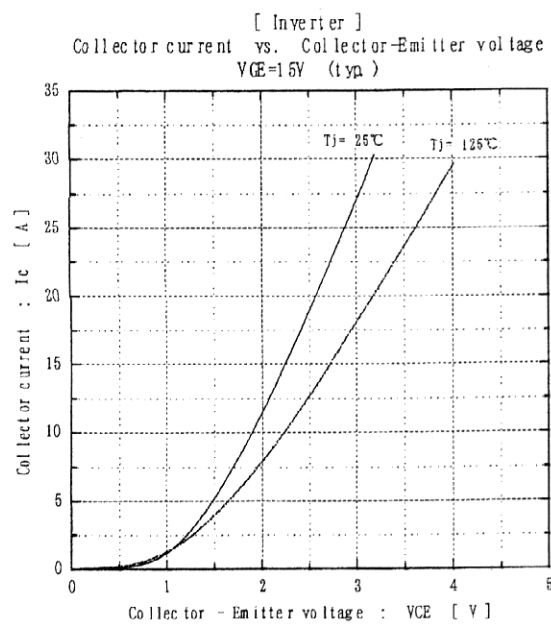
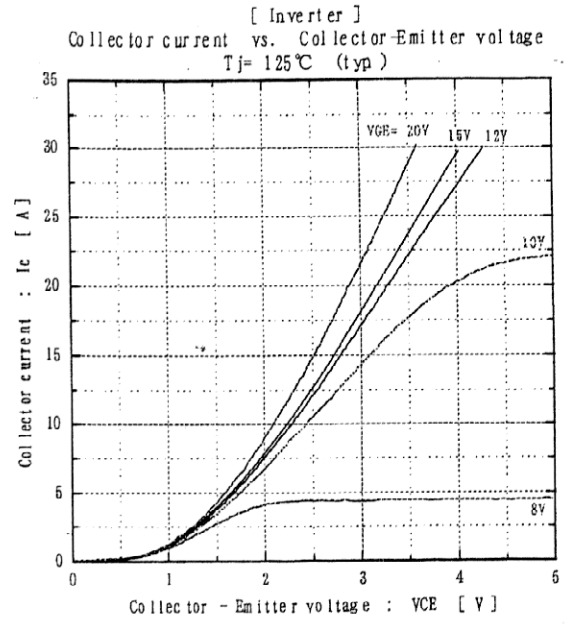
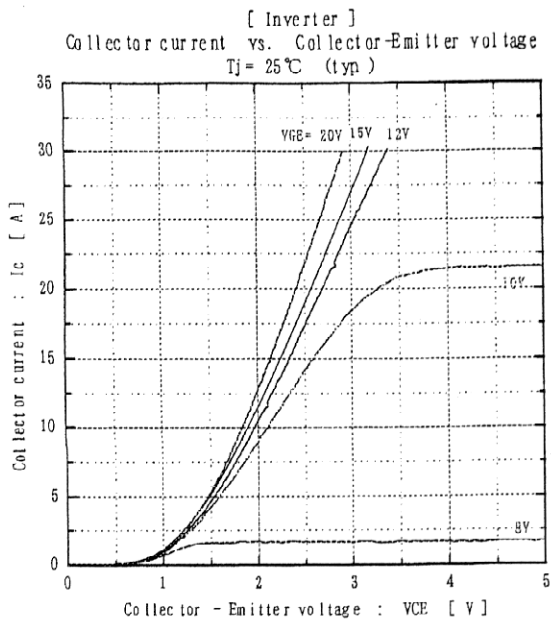
- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
 常温・常湿保存が望ましい。(5~35°C, 45~75%)
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
 急激な温度変化のなきこと。(モジュール表面が結露しないこと)
- Avoid exposure to corrosive gases and dust.
 腐蝕性ガスの発生場所, 塵埃の多い場所は避けること。
- Avoid excessive external force on the module.
 製品に荷重がかからないように 十分注意すること。
- Store modules with unprocessed terminals.
 モジュールの端子は未加工の状態 で保管すること。
- Do not drop or otherwise shock the modules when transporting.
 製品の運搬時に衝撃を与えたり, 落下させたりしないこと。

9. Definitions of switching time (スイッチング時間の定義)

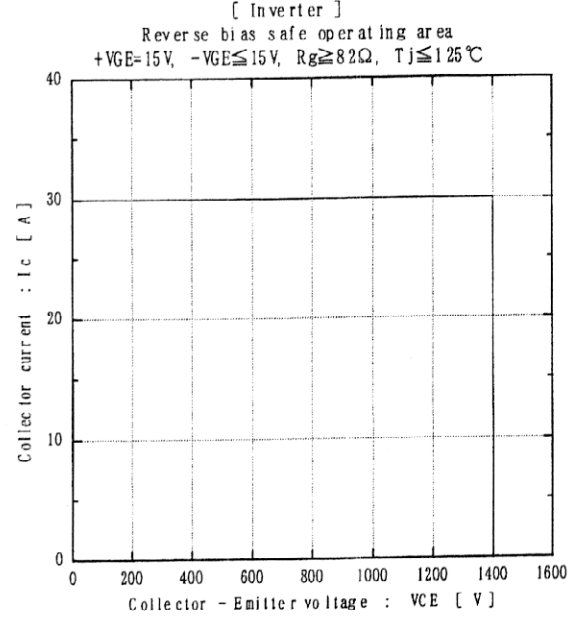
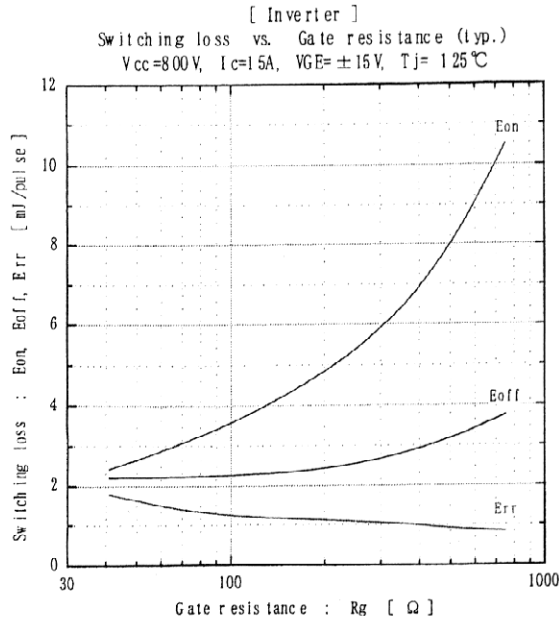
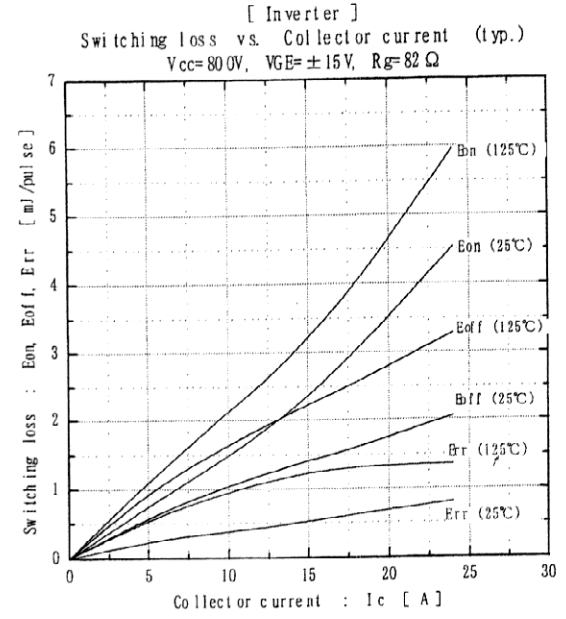
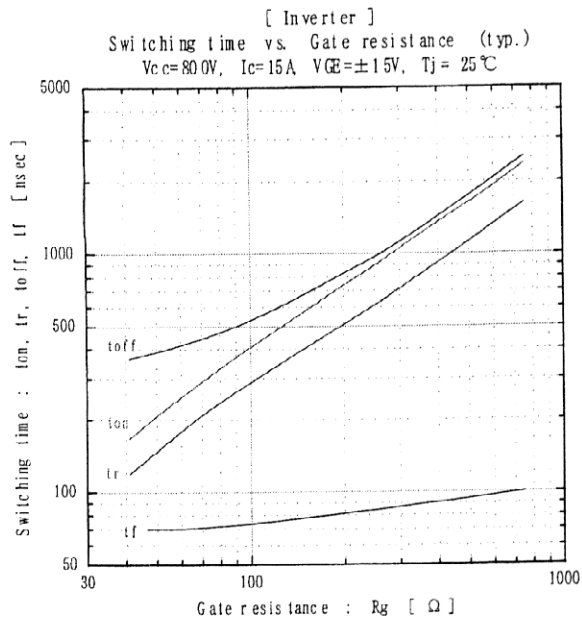
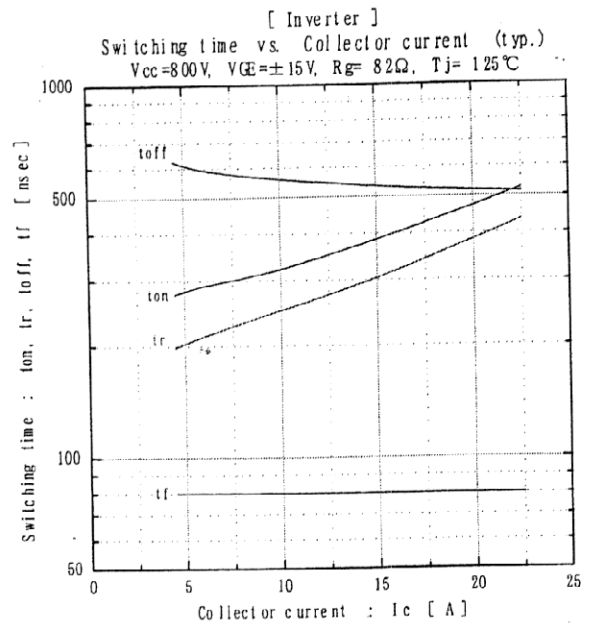
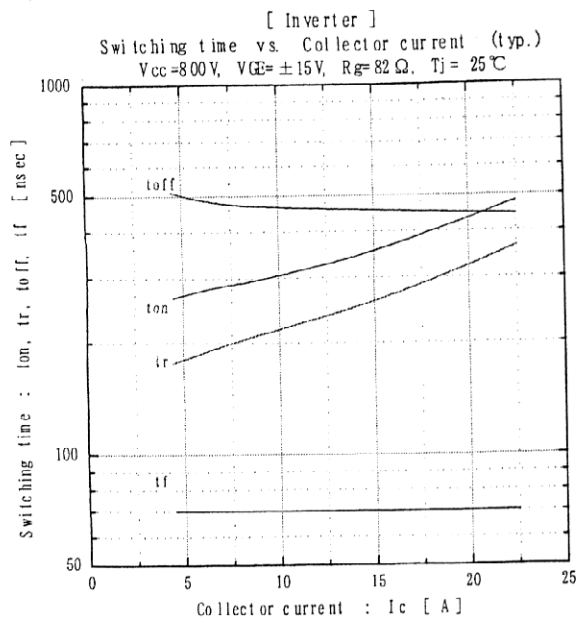


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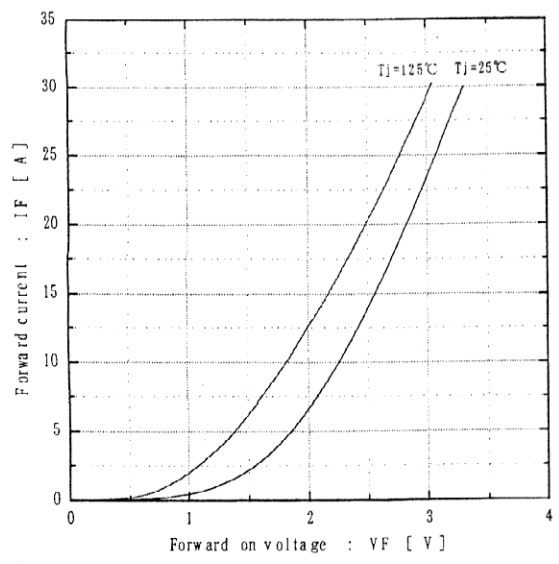


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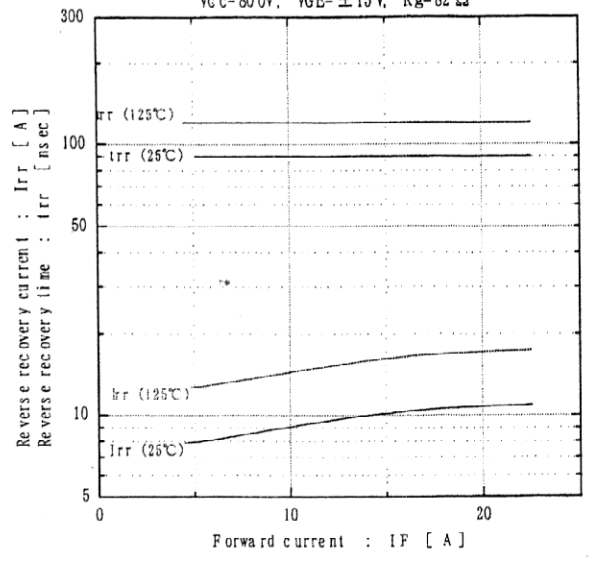


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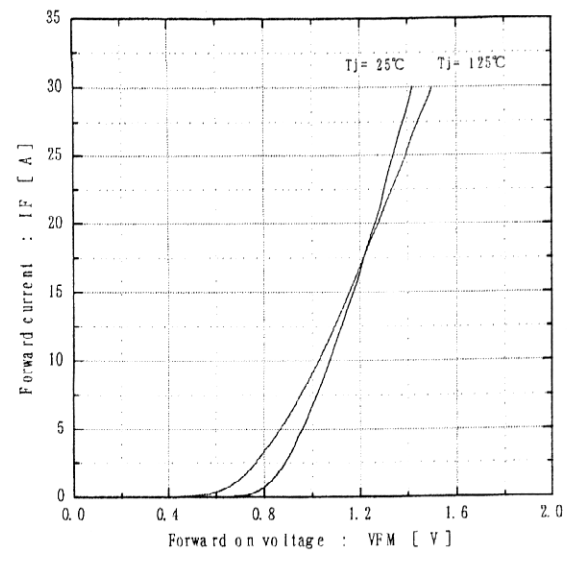
[Inverter]
Forward current vs. Forward on voltage (typ.)



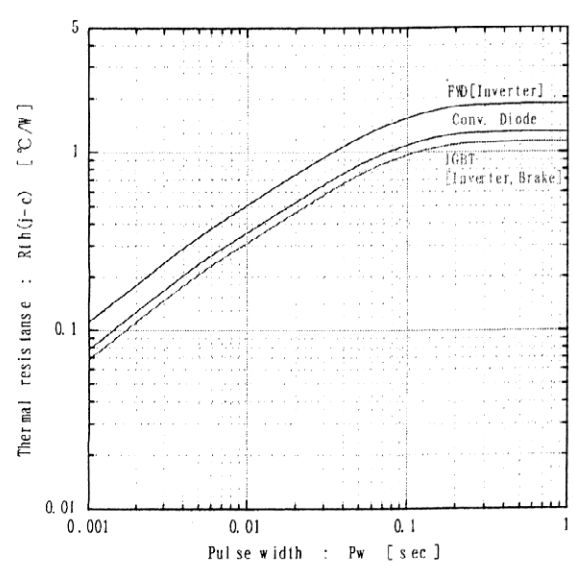
[Inverter]
Reverse recovery characteristics (typ.)
 $V_{ce} = 80 \text{OV}$, $V_{GE} = \pm 15 \text{V}$, $R_g = 82 \Omega$



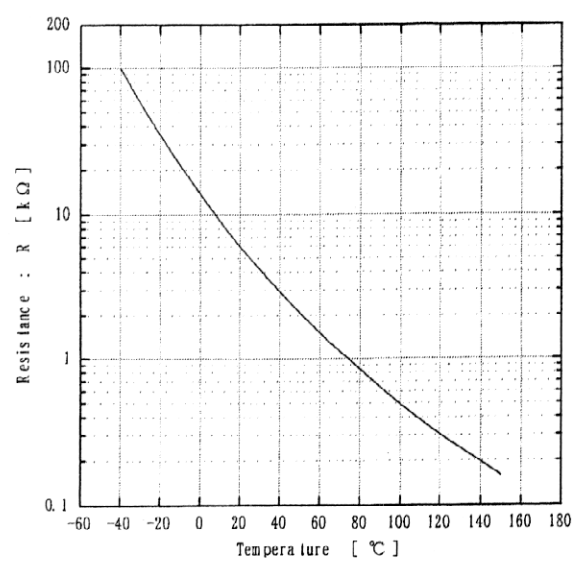
[Converter]
Forward current vs. Forward on voltage (typ.)



Transient thermal resistance



[Thermistor]
Temperature characteristic (typ.)



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